



60V N-Channel Enhancement Mode MOSFET

Voltage 60 V Current 200mA

Features

- RDS(ON), VGS@10V, ID@600mA<3Ω
- RDS(ON), VGS@4.5V, ID@200mA<4Ω
- Advanced Trench Process Technology
- Specially Designed for Relay driver, Speed line drive, etc.
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

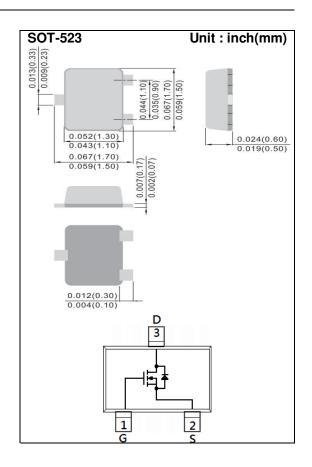
Mechanical Data

• Case: SOT-523 Package

Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.00007 ounces, 0.002 grams

Marking : E2B



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	60	V
Gate-Source Voltage		V_{GS}	<u>+</u> 30	V
Continuous Drain Current		I _D	200	mA
Pulsed Drain Current		I _{DM}	800	mA
Power Dissipation	T _A =25°C	Б	300	mW
	Derate above 25°C	P _D	4	mW/°C
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C
Typical Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	417	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	$V_{GS}=0V,I_D=250uA$	60	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	1.0	1.8	2.5	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =600mA	-	1.3	3	Ω	
		V _{GS} =4.5V,I _D =200mA	-	1.7	4		
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =60V, V_{GS} =0V	-	-	1	uA	
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm30V, V_{DS}=0V$	-	-	<u>+</u> 100	nA	
Dynamic (Note 4)							
Total Gate Charge	Q_g	V_{DS} =15V, I_{D} =600mA, V_{GS} =4.5V	-	0.82	-	nC	
Gate-Source Charge	Q_gs		-	0.53	-		
Gate-Drain Charge	Q_gd	V _{GS} =4.5V	-	0.22	-		
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V, f=1.0MHZ	-	34	-	pF	
Output Capacitance	Coss		-	11	-		
Reverse Transfer Capacitance	Crss	I= I.UIVINZ	-	3.0	-		
Turn-On Delay Time	td _(on)	\\ 10\\ 600m \	-	2.7	-		
Turn-On Rise Time	tr	$V_{DD}=10V$, $I_{D}=600$ mA, $V_{GS}=10V$, $R_{G}=6\Omega$ (Note 1.2)	-	21	-		
Turn-Off Delay Time	td _(off)		-	3.8	-		
Turn-Off Fall Time	tf	ng=012	-	18	-		
Drain-Source Diode							
Maximum Continuous Drain-Source				-	500	mA	
Diode Forward Current	I _S		_				
Diode Forward Voltage	V_{SD}	I _S =500mA, V _{GS} =0V	-	0.9	1.5	V	

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. mounted on a 1 inch square pad of copper
- 4. Guaranteed by design, not subject to production testing





TYPICAL CHARACTERISTIC CURVES

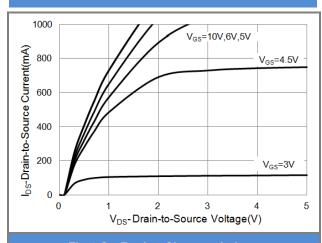


Fig.1 On-Region Characteristics

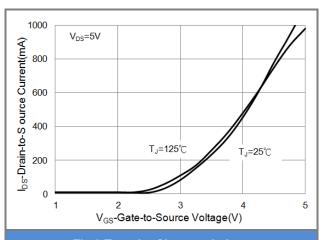


Fig.2 Transfer Characteristics

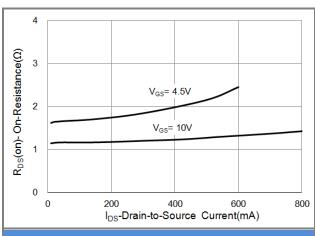


Fig.3 On-Resistance vs. Drain Current

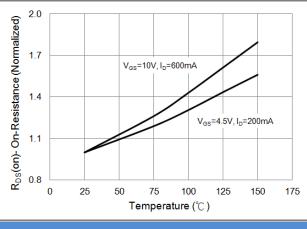


Fig.4 On-Resistance vs. Junction temperature

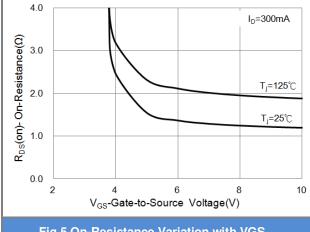


Fig.5 On-Resistance Variation with VGS.

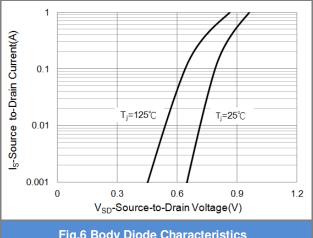


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

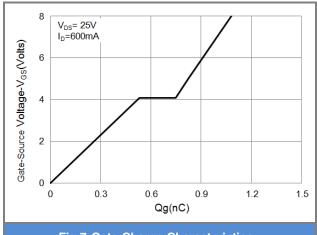


Fig.7 Gate-Charge Characteristics

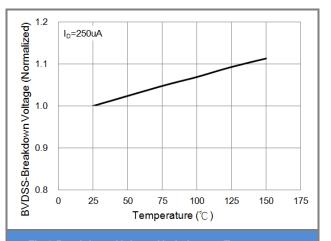


Fig.8 Breakdown Voltage Variation vs. Temperature

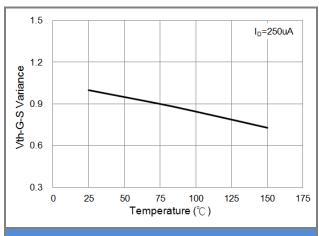


Fig.9 Threshold Voltage Variation with Temperature.

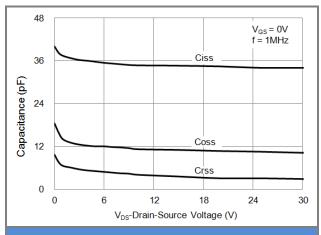


Fig.10 Capacitance vs. Drain-Source Voltage.

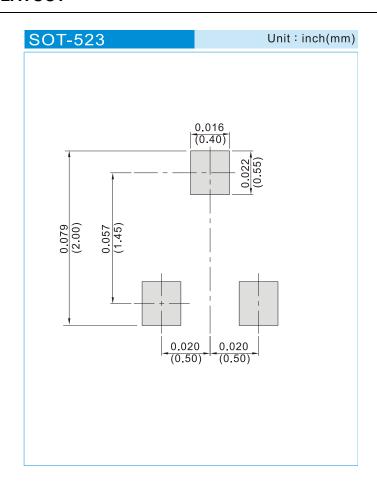




PART NO PACKING CODE VERSION

PART NO PACKING CODE	Package Type	Packing type	Marking	Version
PJE8472B_R1_00001	SOT-523	4K pcs / 7" reel	E2B	Halogen free

MOUNTING PAD LAYOUT







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